

Features

- Supply Voltage: $\pm 3.3\text{V}$ to $\pm 8\text{V}$ or 3.3V to 16V
- Low ON-State Resistance:
typical 4.5Ω at $V_s = \pm 5\text{V}$
- Bandwidth: 150 MHz
- Fast switching times: $t_{\text{ON}} = 200\text{ns}$, $t_{\text{OFF}} = 130\text{ns}$ at $V_s = \pm 5\text{V}$
- Break-Before-Make Switching
- Operation Temperature Range: -40°C to 125°C

Applications

- Industry control systems
- Battery-powered systems
- Audio Signal Routing
- Instrumentation

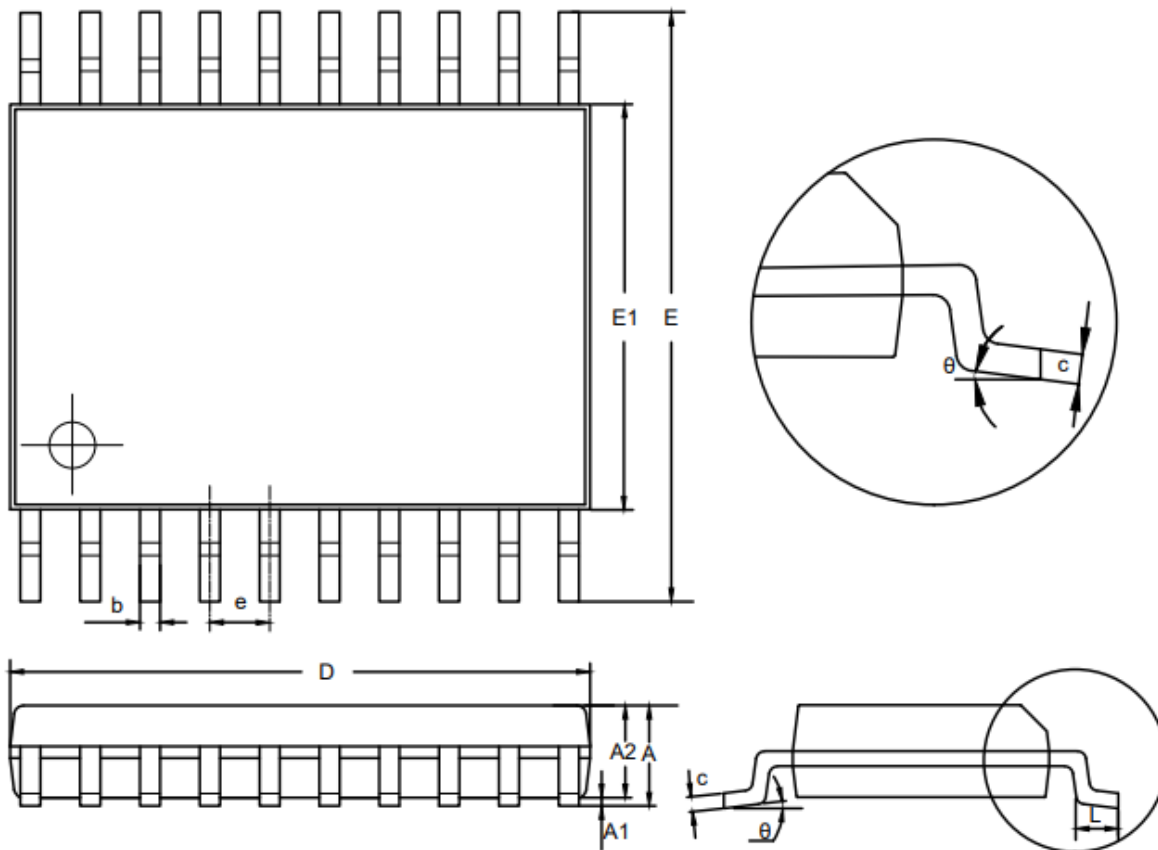
Description

The TPW4425 is a four channel single-pole dual-throw analog switch (SPDT) suitable for use in analog or multiplexer / de-multiplexer applications.

The device is designed on an enhanced process that provides lower power dissipation yet gives high switching speeds. These devices can operate equally well as either multiplexers or de-multiplexers and have an input range that extends to the supplies. All channels exhibit break-before-make switching action, preventing momentary shorting when switching channels.

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NOTES

1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.900	1.200	0.035	0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	6.400	6.600	0.252	0.260
E	6.200	6.600	0.244	0.260
E1	4.300	4.500	0.169	0.177
e	0.650 BSC		0.026 BSC	
L	0.450	0.750	0.018	0.030
θ	0	8°	0	8°

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Revision History

Date	Revision	Notes
2020/7/31	Rev.Pre	Pre-released version
2020/9/15	Rev.Pre.1	Updated Tape and Reel Information: P0: 4->8, Pin1: Q1->Q2
2020/12/20	Rev.A.0	Released version
2021/10/18	Rev.A.1	Updated the absolute rating of Digital Input Voltage, /E, S2, S1, S0, INx
2023/04/21	Rev.A.2	Added the pin description, the exposed pad is tied to the V _{EE} .

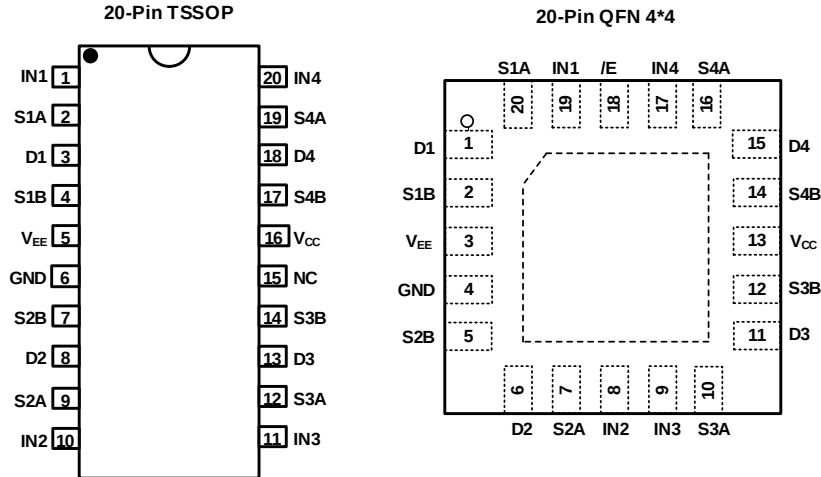
Order Information

Order Number	Operating Temperature Range	Package	Marking Information	MSL	Transport Media, Quantity
TPW4425-QFKR	-40 to 125°C	20-Pin QFN 4*4mm	W4425	3	Tape and Reel, 3000
TPW4425-TS4R Note 1	-40 to 125°C	TSSOP-20	W4425	3	Tape and Reel, 4000

Note 1: Future product, contact 3PEAK factory for more information and sample

Pin Configuration, Description and Functional Table ^{Note 1}

TPW4425, 4ch SPDT



Note: The exposed pad is tied to the V_{EE}

Pin Functions

Pin			I/O	Description
TSSOP20	QFN-20L	Name		
1	19	IN1	I	Logic Control Input 1.
2	20	S1A	IO	Source Terminal 1A. Can be an input or an output.
3	1	D1	IO	Drain Terminal 1. Can be an input or an output.
4	2	S1B	IO	Source Terminal 1B. Can be an input or an output.
5	3	V _{EE}	-	Most Negative Power Supply Potential. In single-supply applications, this pin can be connected to ground.
6	4	GND	-	Ground (0 V) Reference.
7	5	S2B	IO	Source Terminal 2B. Can be an input or an output.
8	6	D2	IO	Drain Terminal 2. Can be an input or an output.
9	7	S2A	IO	Source Terminal 2A. Can be an input or an output.
10	8	IN2	I	Logic Control Input 2.
11	9	IN3	I	Logic Control Input 3.
12	10	S3A	IO	Source Terminal 3A. Can be an input or an output.
13	11	D3	IO	Drain Terminal 3. Can be an input or an output.

16V General Purpose Analog Switch

14	12	S3B	IO	Source Terminal 3B. Can be an input or an output.
15	N/A	NC	-	No Connect.
16	13	V _{CC}	-	Most Positive Power Supply Potential.
17	14	S4B	IO	Source Terminal 4B. Can be an input or an output.
18	15	D4	IO	Drain Terminal 4. Can be an input or an output.
19	16	S4A	IO	Source Terminal 4A. Can be an input or an output.
20	17	IN4	I	Logic Control Input 4.
N/A	18	/E	I	Active Low Digital Input. When this pin is high, the device is disabled and all switches are off. When this pin is low, INx logic inputs determine the on switches.
N/A	21	EP	-	Exposed Pad. The exposed pad is tied to the V _{EE} .

Functional Table

/E	Inx	SxA	SxB
1	X	OFF	OFF
0	0	OFF	ON
0	1	ON	OFF

X = Don't care

Absolute Maximum Ratings ^{Note 1}

Parameters	Rating
Supply Voltage, $V_{CC} - V_{EE}$	-0.5V to 18V
Analog Switch Voltage	$V_{EE} - 0.5V$ to $V_{CC} + 0.5V$
Analog Switch Current	$\pm 200mA$
Analog Switch Diode Current	$\pm 20mA$
Digital Input Voltage, /E, S2, S1, S0, INx	GND-0.3V to $V_{CC} + 0.5V$
Digital Input Diode Current	$\pm 20mA$
Maximum Junction Temperature	150°C
Storage Temperature Range	-65 to 150°C
Lead Temperature (Soldering, 10 sec)	260°C

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

ESD Rating

Symbol	Parameter	Condition	Minimum Level	Unit
HBM	Human Body Model ESD	ANSI/ESDA/JEDEC JS-001	4	kV
CDM	Charged Device Model ESD	ANSI/ESDA/JEDEC JS-002	1	kV

Recommended Operating Conditions ^{Note 1}

Over operating temperature range

Parameters	Min	Max	Unit
Supply Voltage, $V_{CC} - V_{EE}$	3.3	16	V
Select Input Voltage ^{Note1}	0	V_{CC}	V
Input Transition Rise and Fall Rate		100	ns/V
Switch I/O Port Voltage ^{Note2}	V_{EE}	V_{CC}	V
Operating Temperature Range	-40	125	°C

Note 1: Select input must be held HIGH or LOW and it must not float.

Note 2: The voltage of V_{CC} , V_{EE} need be in the range of $V_{CC} - V_{EE}$

Electrical Characteristics

Dual Supply, $V_{CC} = 5V$, $V_{EE} = -8V$, GND = 0V, unless otherwise noted.

Symbol	Parameter	Conditions	V_{CC} / V_{EE} (V)	25°C	-40°C to 85°C	-40°C to 125°C	Limit	Unit
Power Supply								
I _{CC}	Quiescent Supply Current	V _{IN} = 0V or V _{CC}		0.1	1	5	Max	μA
		V _{IN} = 1.8V(应用场景)		70	80	85	Max	μA
		V _{IN} = 3.3V(应用场景)		20	25	30	Max	μA
Digital Input (V _{IN})								
V _{IH}	Input Voltage High				1.5	1.5	Min	V
V _{IL}	Input Voltage Low				0.5	0.5	Max	V
I _{IN}	Control Input Leakage	V _{IN} = 0V or V _{CC}		±0.4	±1	±1	Max	μA
Analog Switch								
R _{ON}		I _{OUT} = 10mA, V _{IS} = V _{CC} or V _{EE}		4			Typ	Ω
				4.5	6.5	7.5	Max	Ω
ΔR _{ON}	On Resistance Match between Channels	I _{OUT} = 10mA, V _{IS} = V _{CC} or V _{EE}		0.25	0.3	0.35	Max	Ω
R _{FLAT(ON)}	On Resistance Flatness	I _{OUT} = 10mA, V _{IS} = V _{CC} or V _{EE}		1.2	1.6	1.9	Max	Ω
I _{CH(OFF)}	Switch OFF Leakage Current on Channel	V _{IS} = 4V, V _{OS} = -7V; or V _{IS} = -7V, V _{OS} = 4V		±0.1	±1	±1	Max	μA
I _{COM(OFF)}	Switch OFF Leakage Current on Common	V _{IS} = 4V, V _{OS} = -7V; or V _{IS} = -7V, V _{OS} = 4V		±0.1	±1	±1	Max	μA
I _(ON)	Switch ON Leakage Current	V _{IS} = V _{OS} = 4V or -7V		±0.1	±1	±1	Max	μA
Dynamic Characteristics								
t _{ON}	Switch turn-on time	V _{IS} = 2.5V, Figure 4		160	180	200	Max	ns
t _{OFF}	Switch turn-off time	V _{IS} = 2.5V, Figure 4		120	130	140	Max	ns
	Break before make time	V _{IS} = 2.5V, Figure 5		55			Typ	ns
t _{ON(EN)}	Switch enable time	V _{IS} = 2.5V, Figure 6		120	130	140	Max	ns
t _{OFF(EN)}	Switch disable time	V _{IS} = 2.5V, Figure 6		170	190	210	Max	ns
	Charge Injection	V _{GEN} = 0V, Figure 7		12.5			Typ	pC
	OFF-Isolation	f = 1MHz, R _L = 50Ω, C _L = 5pF		-64			Typ	dB
	Channel to Channel Crosstalk	f = 1MHz, R _L = 50Ω, C _L = 5pF		-64			Typ	dB
BW	Bandwidth	R _L = 50Ω, C _L = 5pF		150			Typ	MHz
THD+N	Total Harmonic Distortion + Noise	R _L = 110Ω, V _s =5Vpp, f = 1kHz		0.3			Typ	%
Capacitance								
C _{IN}	Switch Input Capacitance	V _s = 0V, f = 1MHz		20			Typ	pF
C _{COM}	Common Output Capacitance	V _s = 0V, f = 1MHz		30			Typ	pF

Dual Supply, $V_{CC} = 4.5$ to $5.5V$, $V_{EE} = -4.5$ to $5.5V$, $GND = 0V$, unless otherwise noted.

Symbol	Parameter	Conditions	V_{CC} / V_{EE} (V)	25°C	-40°C to 85°C	-40°C to 125°C	Limit	Unit
Power Supply								
I_{CC}	Quiescent Supply Current	$V_{IN} = 0V$ or V_{CC}	5.5/-5.5	0.1	1	1	Max	μA
Digital Input (V_{IN})								
V_{IH}	Input Voltage High				1.5	1.5	Min	V
V_{IL}	Input Voltage Low				0.5	0.5	Max	V
I_{IN}	Control Input Leakage	$V_{IN} = 0V$ or V_{CC}	5.5/-5.5	± 0.4	± 1	± 1	Max	μA
Analog Switch								
R_{ON}		$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}	4.5/-4.5	4.5			Typ	Ω
				5	7	8	Max	Ω
ΔR_{ON}	On Resistance Match between Channels	$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}	4.5/-4.5	0.25	0.3	0.35	Max	Ω
$R_{FLAT(ON)}$	On Resistance Flatness	$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}	4.5/-4.5	1.5	1.7	2	Max	Ω
$I_{CH(OFF)}$	Switch OFF Leakage Current on Channel	$V_{IS} = 4.5V$, $V_{OS} = -4.5V$; or $V_{IS} = -4.5V$, $V_{OS} = 4.5V$	5.5/-5.5	± 0.1	± 1	± 1	Max	μA
$I_{COM(OFF)}$	Switch OFF Leakage Current on Common	$V_{IS} = 4.5V$, $V_{OS} = -4.5V$; or $V_{IS} = -4.5V$, $V_{OS} = 4.5V$	5.5/-5.5	± 0.1	± 1	± 1	Max	μA
$I_{(ON)}$	Switch ON Leakage Current	$V_{IS} = V_{OS} = 4.5V$ or $-4.5V$	5.5/-5.5	± 0.1	± 1	± 1	Max	μA
Dynamic Characteristics								
t_{ON}	Switch turn-on time	$V_{IS} = 2.5V$, Figure 4	4.5/-4.5	200	230	250	Max	ns
t_{OFF}	Switch turn-off time	$V_{IS} = 2.5V$, Figure 4	4.5/-4.5	130	140	150	Max	ns
	Break before make time	$V_{IS} = 2.5V$, Figure 5	4.5/-4.5	60			Typ	ns
$t_{ON(EN)}$	Switch enable time	$V_{IS} = 2.5V$, Figure 6	4.5/-4.5	130	150	160	Max	ns
$t_{OFF(EN)}$	Switch disable time	$V_{IS} = 2.5V$, Figure 6	4.5/-4.5	190	230	250	Max	ns
	Charge Injection	$V_{GEN} = 0V$, Figure 7	5/-5	12.5			Typ	pC
	OFF-Isolation	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$	5/-5	-64			Typ	dB
	Channel to Channel Crosstalk	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$	5/-5	-64			Typ	dB
BW	Bandwidth	$R_L = 50\Omega$, $C_L = 5pF$	5/-5	150			Typ	MHz
THD+N	Total Harmonic Distortion + Noise	$R_L = 110\Omega$, $V_S = 5V_{pp}$, $f = 1kHz$	5/-5	0.3			Typ	%
Capacitance								
C_{IN}	Switch Input Capacitance	$V_S = 0V$, $f = 1MHz$	5/-5	20			Typ	pF
C_{COM}	Common Output Capacitance	$V_S = 0V$, $f = 1MHz$	5/-5	30			Typ	pF

Single Supply, $V_{CC} = 10.8V$ to $13.2V$, $V_{EE} = 0V$, $GND = 0V$, unless otherwise noted.

Symbol	Parameter	Conditions	V _{CC}	25°C	-40°C to 85°C	-40°C to 125°C	Limit	Unit
Power Supply								
I _{CC}	Quiescent Supply Current	V _{IN} = 0V or V _{CC}	13.2	0.1	1	1	Max	µA
		V _{IN} = 5V	13.2	300	350	350	Max	µA
Digital Input (V _{IN})								
V _{IH}	Input Voltage High				2.0	2.0	Min	V
V _{IL}	Input Voltage Low				0.6	0.6	Max	V
I _{IN}	Control Input Leakage	V _{IN} = 0V or V _{CC}	13.2	±0.4	±1	±1	Max	µA
Analog Switch								
R _{ON}		I _{OUT} = 10mA, V _{IS} = V _{CC} or V _{EE}	10.8	4			Typ	Ω
				4.5	6.5	7.5	Max	Ω
ΔR _{ON}	On Resistance Match between Channels	I _{OUT} = 10mA, V _{IS} = V _{CC} or V _{EE}	10.8	0.25	0.3	0.35	Max	Ω
R _{FLAT(ON)}	On Resistance Flatness	I _{OUT} = 10mA, V _{IS} = V _{CC} or V _{EE}	10.8	1.4	1.6	1.9	Max	Ω
I _{CH(OFF)}	Switch OFF Leakage Current on Channel	V _{IS} = 1V, V _{OS} = 10V; or V _{IS} = 10V, V _{OS} = 1V	13.2	±0.1	±1	±1	Max	µA
I _{COM(OFF)}	Switch OFF Leakage Current on Common	V _{IS} = 1V, V _{OS} = 10V; or V _{IS} = 10V, V _{OS} = 1V	13.2	±0.1	±1	±1	Max	µA
I _(ON)	Switch ON Leakage Current	V _{IS} = V _{OS} = 1V or 10V	13.2	±0.1	±1	±1	Max	µA
Dynamic Characteristics								
t _{ON}	Switch turn-on time	V _{IS} = 8V, Figure 4	10.8	150	180	200	Max	ns
t _{OFF}	Switch turn-off time	V _{IS} = 8V, Figure 4	10.8	100	120	130	Max	ns
	Break before make time	V _{IS} = 8V, Figure 5	10.8	55			Typ	ns
t _{ON(EN)}	Switch enable time	V _{IS} = 8V, Figure 6	10.8	90	100	110	Max	ns
t _{OFF(EN)}	Switch disable time	V _{IS} = 8V, Figure 6	10.8	150	180	200	Max	ns
	Charge Injection	V _{GEN} = 6V, Figure 7	12	12.5			Typ	pC
	OFF-Isolation	f = 1MHz, R _L = 50Ω, C _L = 5pF	12	-64			Typ	dB
	Channel to Channel Crosstalk	f = 1MHz, R _L = 50Ω, C _L = 5pF	12	-64			Typ	dB
BW	Bandwidth	R _L = 50Ω, C _L = 5pF	12	150			Typ	MHz
THD+N	Total Harmonic Distortion + Noise	R _L = 110Ω, V _S =5Vpp, f = 1kHz	12	0.3			Typ	%
Capacitance								
C _{IN}	Switch Input Capacitance	V _S = 6V, f = 1MHz	12	20			Typ	pF
C _{COM}	Common Output Capacitance	V _S = 6V, f = 1MHz	12	30			Typ	pF

Single Supply, $V_{CC} = 4.5V$ to $5.5V$, $V_{EE} = 0V$, $GND = 0V$, unless otherwise noted.

Symbol	Parameter	Conditions	V_{CC}	25°C	-40°C to 85°C	-40°C to 125°C	Limit	Unit
Power Supply								
I_{CC}	Quiescent Supply Current	$V_{IN} = 0V$ or V_{CC}	5.5	0.1	1	1	Max	μA
Digital Input (V_{IN})								
V_{IH}	Input Voltage High				1.5	1.5	Min	V
V_{IL}	Input Voltage Low				0.5	0.5	Max	V
I_{IN}	Control Input Leakage	$V_{IN} = 0V$ or V_{CC}	5.5	± 0.4	± 1	± 1	Max	μA
Analog Switch								
R_{ON}		$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}	4.5	8.5			Typ	Ω
				10	12.5	14	Max	Ω
ΔR_{ON}	On Resistance Match between Channels	$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}	4.5	0.3	0.35	0.4	Max	Ω
$R_{FLAT(ON)}$	On Resistance Flatness	$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}	4.5	3.1	3.3	3.5	Max	Ω
$I_{CH(OFF)}$	Switch OFF Leakage Current on Channel	$V_{IS} = 1V$, $V_{OS} = 4.5V$; or $V_{IS} = 4.5V$, $V_{OS} = 1V$	5.5	± 0.1	± 1	± 1	Max	μA
$I_{COM(OFF)}$	Switch OFF Leakage Current on Common	$V_{IS} = 1V$, $V_{OS} = 4.5V$; or $V_{IS} = 4.5V$, $V_{OS} = 1V$	5.5	± 0.1	± 1	± 1	Max	μA
$I_{(ON)}$	Switch ON Leakage Current	$V_{IS} = V_{OS} = 1V$ or $4.5V$	5.5	± 0.1	± 1	± 1	Max	μA
Dynamic Characteristics								
t_{ON}	Switch turn-on time	$V_{IS} = 2.5V$, Figure 4		300	320	350	Max	ns
t_{OFF}	Switch turn-off time	$V_{IS} = 2.5V$, Figure 4		130	150	160	Max	ns
	Break before make time	$V_{IS} = 2.5V$, Figure 5		100			Typ	ns
$t_{ON(EN)}$	Switch enable time	$V_{IS} = 2.5V$, Figure 6		180	200	210	Max	ns
$t_{OFF(EN)}$	Switch disable time	$V_{IS} = 2.5V$, Figure 6		230	260	280	Max	ns
	Charge Injection	$V_{GEN} = 2.5V$, Figure 7	5	5			Typ	pC
	OFF-Isolation	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$	5	-64			Typ	dB
	Channel to Channel Crosstalk	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$	5	-64			Typ	dB
BW	Bandwidth	$R_L = 50\Omega$, $C_L = 5pF$	5	100			Typ	MHz
THD+N	Total Harmonic Distortion + Noise	$R_L = 110\Omega$, $V_S = 3.5V_{pp}$, $f = 1kHz$	5	0.3			Typ	%
Capacitance								
C_{IN}	Switch Input Capacitance	$V_S = 2.5V$, $f = 1MHz$	5	20			Typ	pF
C_{COM}	Common Output Capacitance	$V_S = 2.5V$, $f = 1MHz$	5	30			Typ	pF

Single Supply, $V_{CC} = 3.3V$, $V_{EE} = 0V$, $GND = 0V$, unless otherwise noted.

Symbol	Parameter	Conditions	V_{CC}	25°C	-40°C to 85°C	-40°C to 125°C	Limit	Unit
Power Supply								
I_{CC}	Quiescent Supply Current	$V_{IN} = 0V$ or V_{CC}		0.1	1	1	Max	μA
Digital Input (V_{IN})								
V_{IH}	Input Voltage High				1.4	1.4	Min	V
V_{IL}	Input Voltage Low				0.4	0.4	Max	V
I_{IN}	Control Input Leakage	$V_{IN} = 0V$ or V_{CC}		± 0.4	± 1	± 1	Max	μA
Analog Switch								
R_{ON}		$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}		13.5	15	16.5	Typ	Ω
ΔR_{ON}	On Resistance Match between Channels	$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}		0.25	0.28	0.3	Typ	Ω
$R_{FLAT(ON)}$	On Resistance Flatness	$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}		5.5	7	7.5	Typ	Ω
$I_{CH(OFF)}$	Switch OFF Leakage Current on Channel	$V_{IS} = 0.6V$, $V_{OS} = 3V$; or $V_{IS} = 3V$, $V_{OS} = 0.6V$		± 0.1	± 1	± 1	Max	μA
$I_{COM(OFF)}$	Switch OFF Leakage Current on Common	$V_{IS} = 0.6V$, $V_{OS} = 3V$; or $V_{IS} = 3V$, $V_{OS} = 0.6V$		± 0.1	± 1	± 1	Max	μA
$I_{(ON)}$	Switch ON Leakage Current	$V_{IS} = V_{OS} = 0.6V$ or $3V$		± 0.1	± 1	± 1	Max	μA
Dynamic Characteristics								
t_{ON}	Switch turn-on time	$V_{IS} = 1.5V$, Figure 4		480	500	520	Max	ns
t_{OFF}	Switch turn-off time	$V_{IS} = 1.5V$, Figure 4		190	200	210	Max	ns
	Break before make time	$V_{IS} = 1.5V$, Figure 5		200			Typ	ns
$t_{ON(EN)}$	Switch enable time	$V_{IS} = 1.5V$, Figure 6		300	330	350	Max	ns
$t_{OFF(EN)}$	Switch disable time	$V_{IS} = 1.5V$, Figure 6		410	470	500	Max	ns
	Charge Injection	$V_{GEN} = 1.5V$, Figure 7		10			Typ	pC
	OFF-Isolation	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$		-64			Typ	dB
	Channel to Channel Crosstalk	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$		-64			Typ	dB
BW	Bandwidth	$R_L = 50\Omega$, $C_L = 5pF$		100			Typ	MHz
THD+N	Total Harmonic Distortion + Noise	$R_L = 110\Omega$, $V_S = 2V_{pp}$, $f = 1kHz$		0.6			Typ	%
Capacitance								
C_{IN}	Switch Input Capacitance	$V_S = 1.5V$, $f = 1MHz$	3.3	20			Typ	pF
C_{COM}	Common Output Capacitance	$V_S = 1.5V$, $f = 1MHz$	3.3	30			Typ	pF

Single Supply, $V_{CC} = 16V$, $V_{EE} = 0V$, $GND = 0V$, unless otherwise noted.

Symbol	Parameter	Conditions	V_{CC}	25°C	-40°C to 85°C	-40°C to 125°C	Limit	Unit
Power Supply								
I_{CC}	Quiescent Supply Current	$V_{IN} = 0V$ or V_{CC}		0.1	1	1	Max	μA
Digital Input (V_{IN})								
V_{IH}	Input Voltage High					2.4	Min	V
V_{IL}	Input Voltage Low					0.6	Max	V
I_{IN}	Control Input Leakage	$V_{IN} = 0V$ or V_{CC}		± 0.4	± 1	± 1	Typ	μA
Analog Switch								
R_{ON}		$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}		3.5	5	6	Typ	Ω
ΔR_{ON}	On Resistance Match between Channels	$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}		0.25	0.28	0.3	Typ	Ω
$R_{FLAT(ON)}$	On Resistance Flatness	$I_{OUT} = 10mA$, $V_{IS} = V_{CC}$ or V_{EE}		1.2	1.5	1.8	Typ	Ω
$I_{CH(OFF)}$	Switch OFF Leakage Current on Channel	$V_{IS} = 1V$, $V_{OS} = 14V$; or $V_{IS} = 14V$, $V_{OS} = 1V$		± 0.1	± 1	± 1	Typ	μA
$I_{COM(OFF)}$	Switch OFF Leakage Current on Common	$V_{IS} = 1V$, $V_{OS} = 14V$; or $V_{IS} = 14V$, $V_{OS} = 1V$		± 0.1	± 1	± 1	Typ	μA
$I_{(ON)}$	Switch ON Leakage Current	$V_{IS} = V_{OS} = 1V$ or $14V$		± 0.1	± 1	± 1	Typ	μA
Dynamic Characteristics								
t_{ON}	Switch turn-on time	$V_{IS} = 8V$, Figure 4		140	170	190	Typ	ns
t_{OFF}	Switch turn-off time	$V_{IS} = 8V$, Figure 4		90	100	110	Typ	ns
	Break before make time	$V_{IS} = 8V$, Figure 5		55			Typ	ns
$t_{ON(EN)}$	Switch enable time	$V_{IS} = 8V$, Figure 6		80	90	100	Typ	ns
$t_{OFF(EN)}$	Switch disable time	$V_{IS} = 8V$, Figure 6		140	160	180	Typ	ns
	Charge Injection	$V_{GEN} = 8V$, Figure 7		10			Typ	pC
	OFF-Isolation	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$		-64			Typ	dB
	Channel to Channel Crosstalk	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$		-64			Typ	dB
BW	Bandwidth	$R_L = 50\Omega$, $C_L = 5pF$		150			Typ	MHz
THD+N	Total Harmonic Distortion + Noise	$R_L = 110\Omega$, $V_S = 7V_{pp}$, $f = 1kHz$		0.1			Typ	%
Capacitance								
C_{IN}	Switch Input Capacitance	$V_S = 8V$, $f = 1MHz$		20			Typ	pF
C_{COM}	Common Output Capacitance	$V_S = 8V$, $f = 1MHz$		30			Typ	pF

Typical Performance Characteristics

$V_{CC} = 5V$, unless otherwise specified.

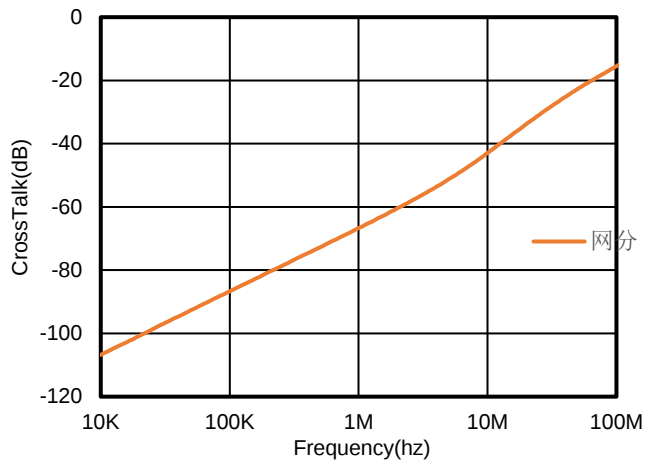


Figure 1. Off-Isolation, $V_{CC} = 5V$, $V_{EE} = -8V$

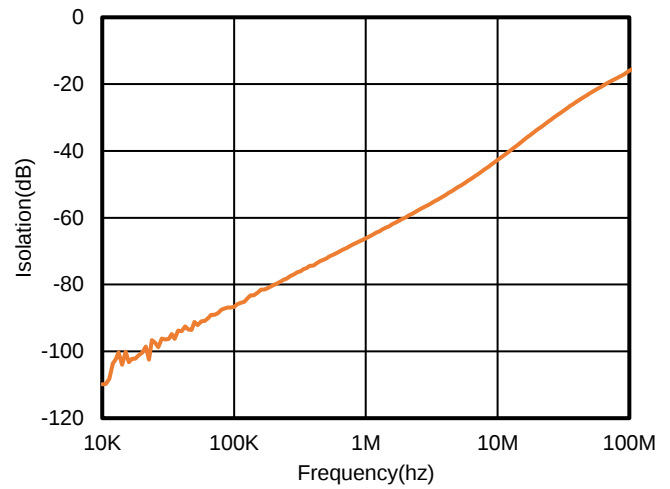


Figure 2. Crosstalk, $V_{CC} = 5V$, $V_{EE} = -8V$

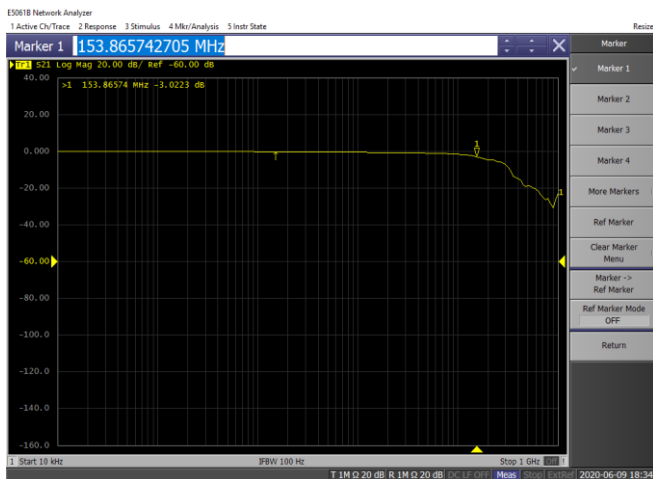


Figure 3. Bandwidth, $V_{CC} = 5V$, $V_{EE} = -8V$

Test Circuit and Waveforms

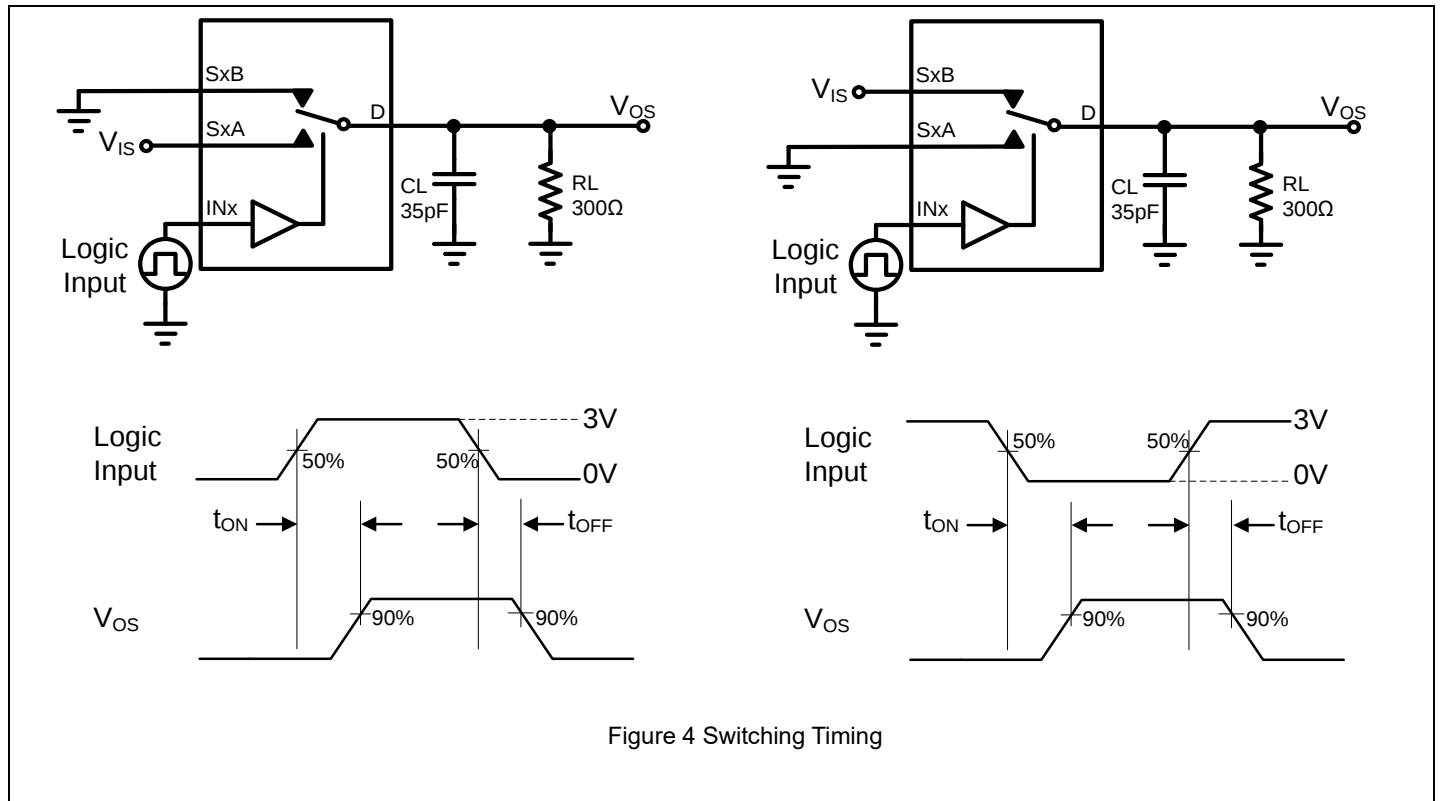


Figure 4 Switching Timing

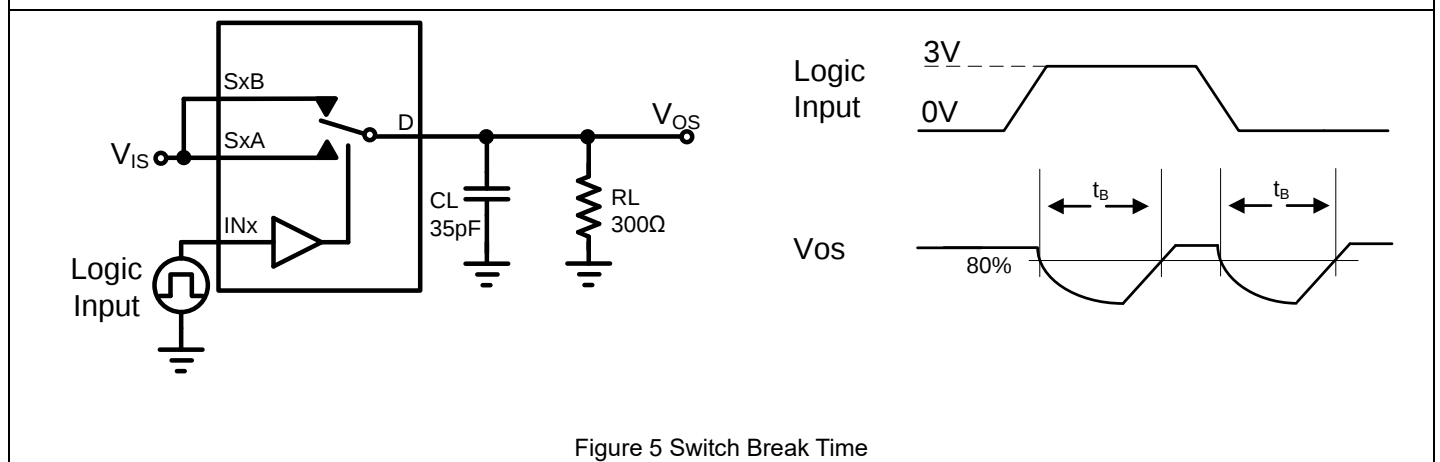


Figure 5 Switch Break Time

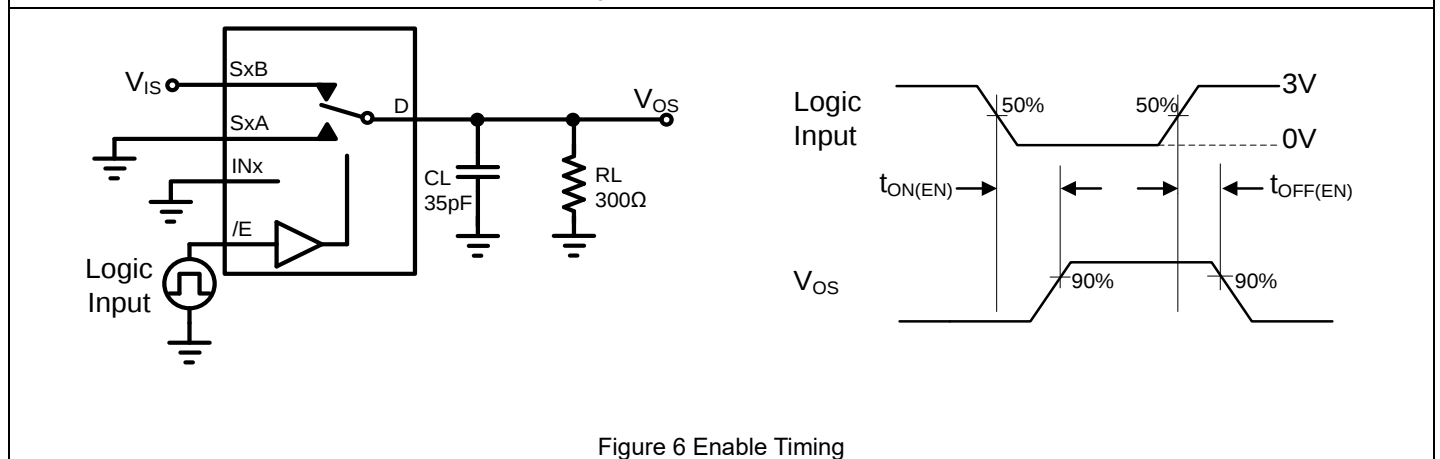


Figure 6 Enable Timing

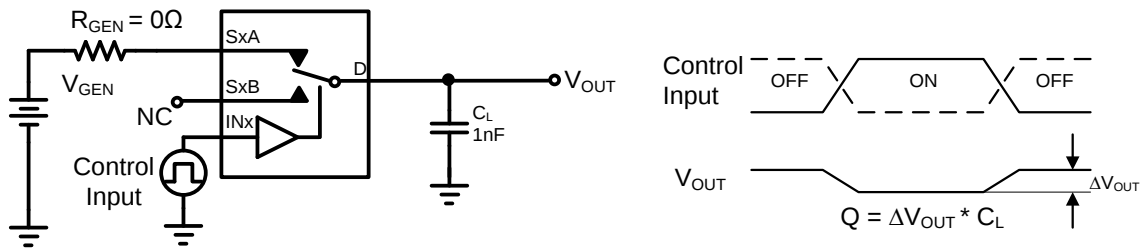


Figure 7 Charge Injection

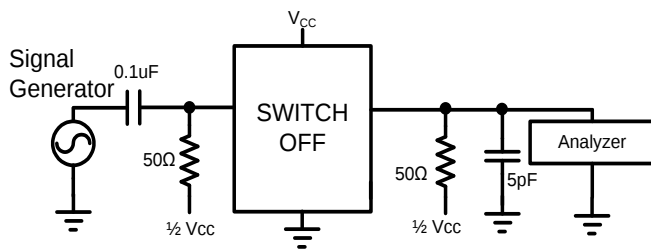


Figure 8 Off Isolation

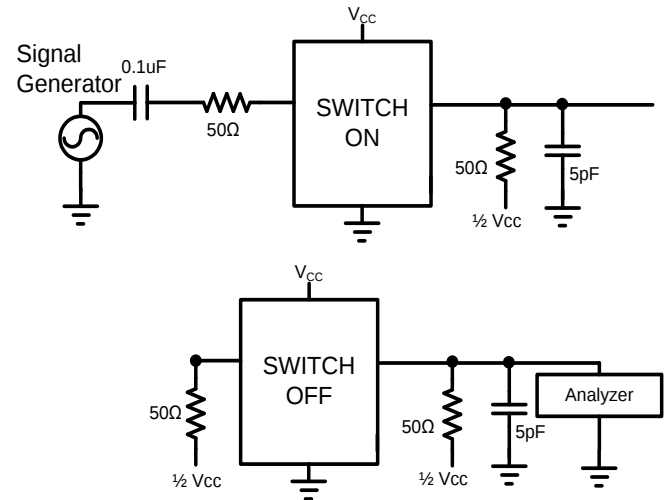
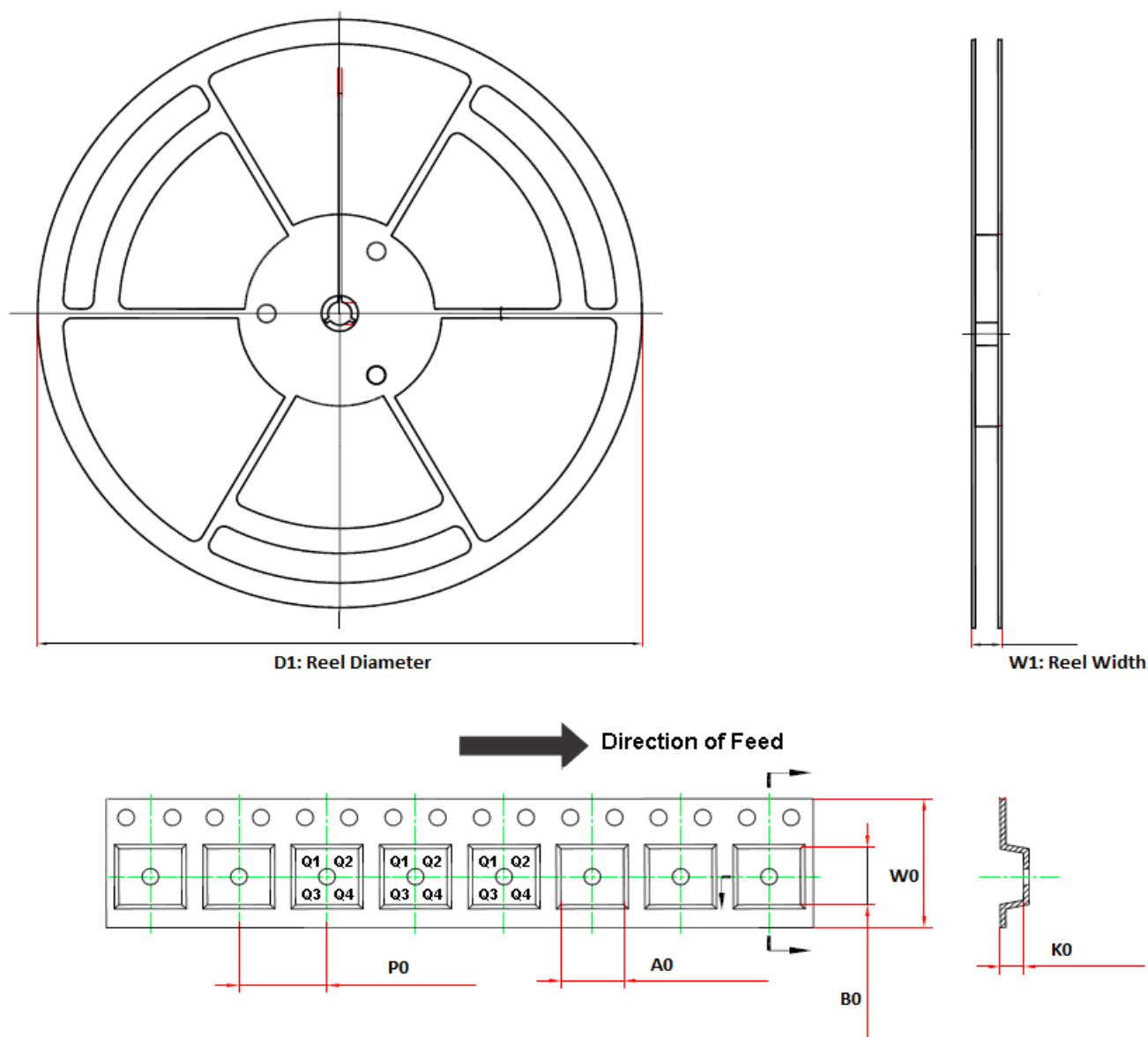


Figure 9 Crosstalk

Application Information

A 0.1- μ F bypass capacitor on VCC and GND is recommended to prevent power disturbance, another 0.1- μ F bypass capacitor on VEE and GND is also recommended if the VSS is not connected to GND.

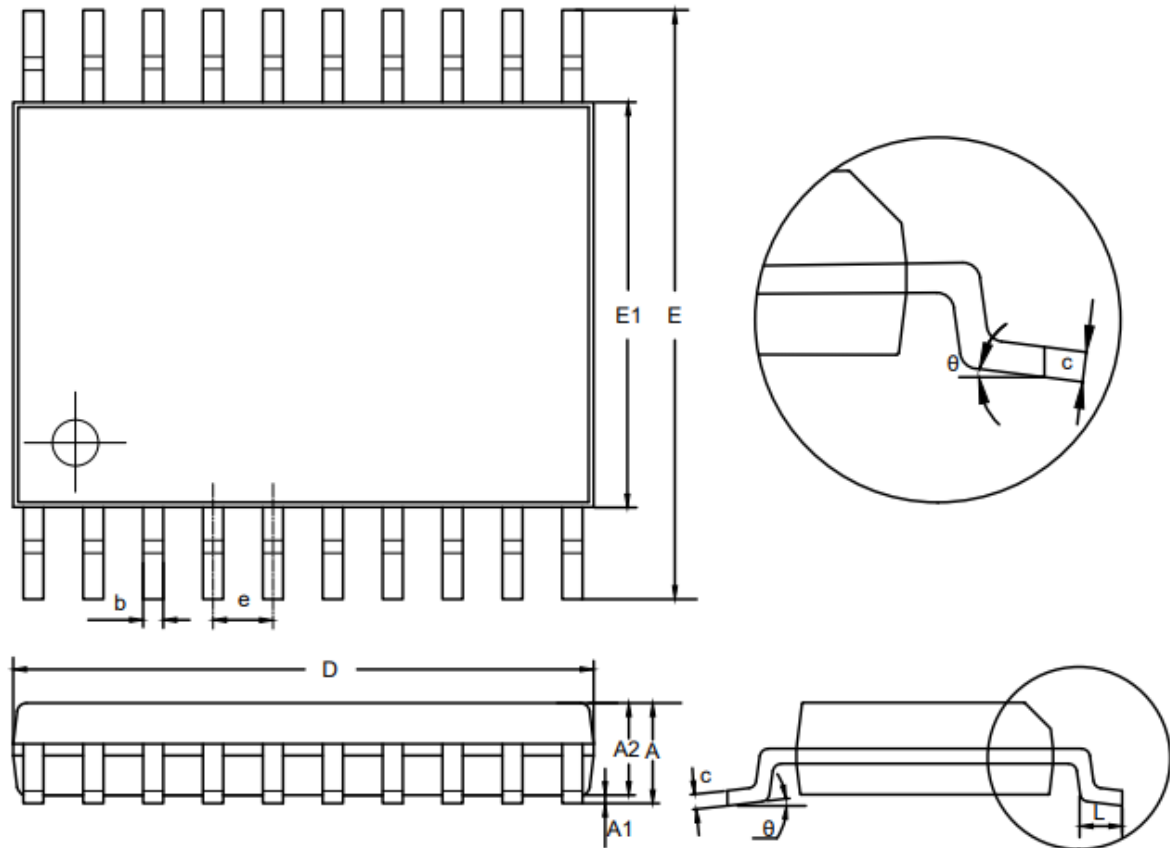
Tape and Reel Information



Order Number	Package	D1 (mm)	W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	W0 (mm)	Pin1 Quadrant
TPW4425-QFKR	20Pin QFN	330	17.6	4.3	4.3	1.1	8	12	Q2

Package Outline Dimensions

TSSOP20



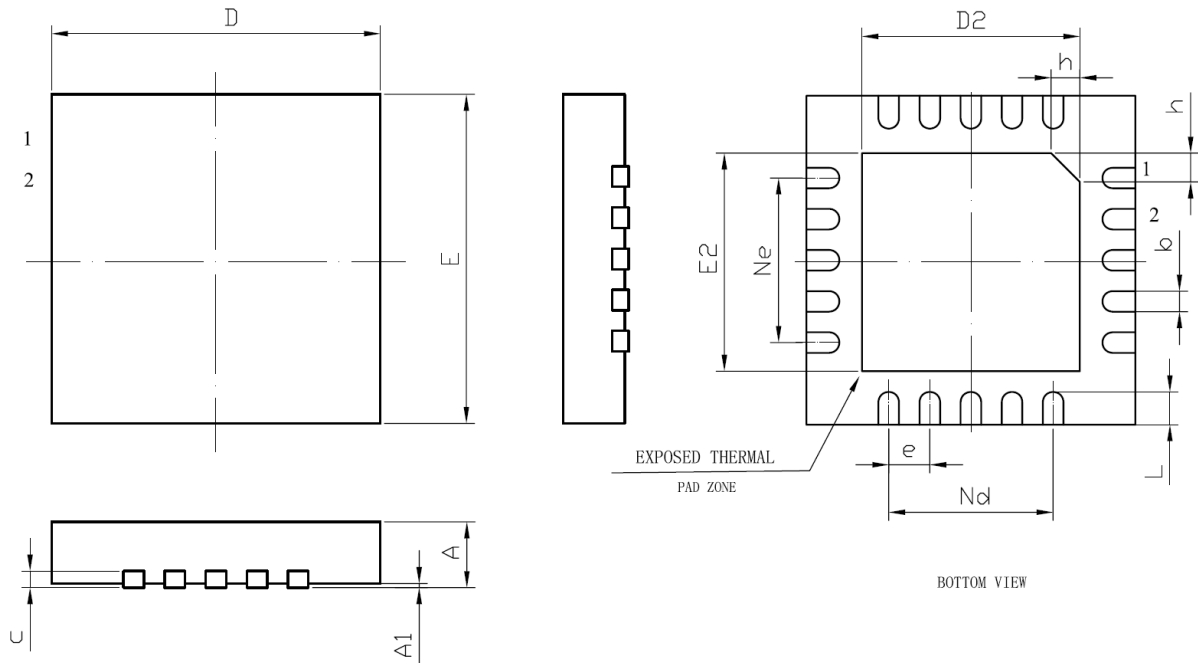
NOTES

1. Do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.900	1.200	0.035	0.047
A1	0.050	0.150	0.002	0.006
A2	0.800	1.050	0.031	0.041
b	0.190	0.300	0.007	0.012
c	0.090	0.200	0.004	0.008
D	6.400	6.600	0.252	0.260
E	6.200	6.600	0.244	0.260
E1	4.300	4.500	0.169	0.177
e	0.650 BSC		0.026 BSC	
L	0.450	0.750	0.018	0.030
θ	0	8°	0	8°

Package Outline Dimensions

QFN-20



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	—	0.02	0.05
b	0.18	0.25	0.30
c	0.18	0.20	0.25
D	3.90	4.00	4.10
D2	2.55	2.65	2.75
e	0.50BSC		
Ne	2.00BSC		
Nd	2.00BSC		
E	3.90	4.00	4.10
E2	2.55	2.65	2.75
L	0.35	0.40	0.45
h	0.30	0.35	0.40

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